NSN 5961-00-290-1880

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Inclosure Material:

Ceramic

Overall Length:

0.610 inches

Overall Width:

0.393 inches

Mounting Facility Quantity:

2

Internal Configuration:

Junction contact

Electrode Internally-electrically Connected To Case:

Collector

Mounting Method:

Unthreaded hole

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

65.0 breakdown voltage, collector-to-base, emitter open

Current Rating Per Characteristic:

9.00 amperes all primaries

Power Rating Per Characteristic:

117.0 watts small-signal input power, common-collector absolute

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Terminal Type And Quantity:

3 tab, solder lug

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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